

**SANYO****Switching Applications (with Bias Resistance)****Applications**

- Switching circuits, inverter circuits, interface circuits, driver circuits.

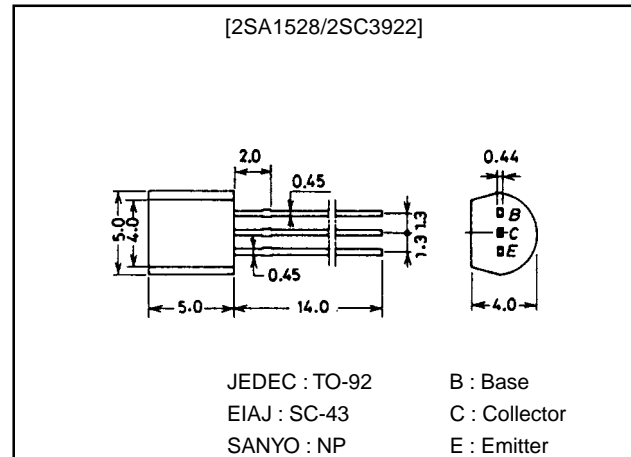
**Features**

- On-chip bias resistance :  $R1=2.2k\Omega$ ,  $R2=10k\Omega$ .
- Large current capacity :  $I_C=500mA$ .

**Package Dimensions**

unit:mm

2003A



() : 2SA1528

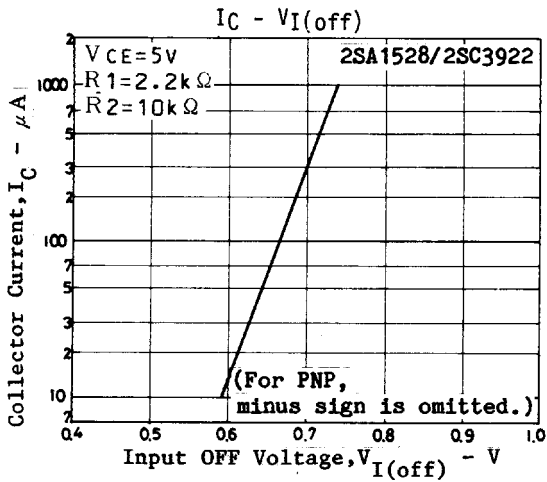
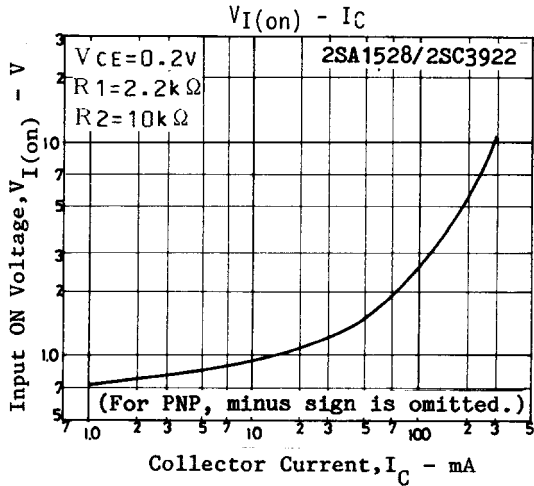
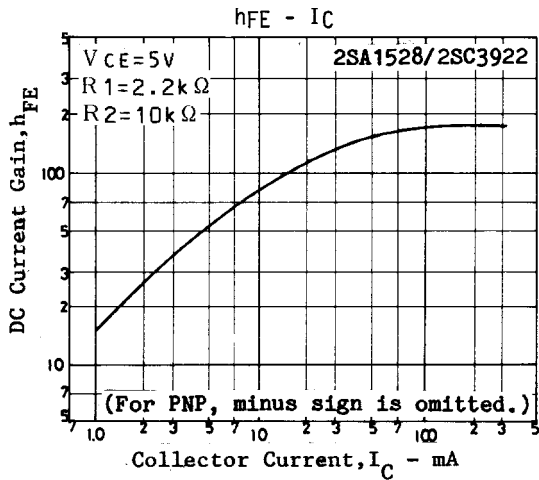
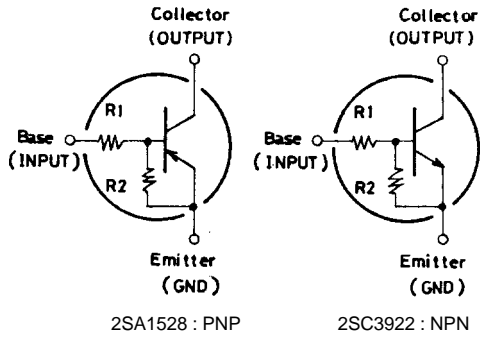
**Specifications****Absolute Maximum Ratings at  $T_a = 25^\circ C$** 

Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	$V_{CBO}$		(-)50	V
Collector-to-Emitter Voltage	$V_{CEO}$		(-)50	V
Emitter-to-Base Voltage	$V_{EBO}$		(-)6	V
Collector Current	$I_C$		(-)500	mA
Collector Current (Pulse)	$I_{CP}$		(-)800	mA
Collector Dissipation	$P_C$		600	mW
Junction Temperature	$T_J$		150	$^\circ C$
Storage Temperature	$T_{stg}$		-55 to +150	$^\circ C$

**Electrical Characteristics at  $T_a = 25^\circ C$** 

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Collector Cutoff Current	$I_{CBO}$	$V_{CB}=(-)40V, I_E=0$			(-)0.1	$\mu A$
	$I_{CEO}$	$V_{CE}=(-)40V, I_B=0$			(-)0.5	$\mu A$
Emitter Cutoff Current	$I_{EBO}$	$V_{EB}=(-)5V, I_C=0$	(-)315	(-)410	(-)590	$\mu A$
DC Current Gain	$h_{FE}$	$V_{CE}=(-)5V, I_C=(-)10mA$	50			
Gain-Bandwidth Product	$f_T$	$V_{CE}=(-)10V, I_C=(-)5mA$		250		MHz
				(200)		MHz
Output Capacitance	$C_{ob}$	$V_{CB}=(-)10V, f=1MHz$		3.7		pF
				(5.5)		pF
Collector-to-Emitter Saturation Voltage	$V_{CE(sat)}$	$I_C=(-)50mA, I_B=(-)2.5mA$		(-)0.1	(-)0.3	V
Collector-to-Base Breakdown Voltage	$V_{(BR)CBO}$	$I_C=(-)10\mu A, I_E=0$	(-)50			V
Collector-to-Emitter Breakdown Voltage	$V_{(BR)CEO}$	$I_C=(-)100\mu A, R_{BE}=\infty$	(-)50			V
Input OFF-State Voltage	$V_{I(off)}$	$V_{CE}=(-)5V, I_C=(-)100\mu A$	(-)0.5	(-)0.67	(-)0.9	V
Input ON-State Voltage	$V_{I(on)}$	$V_{CE}=(-)0.2V, I_C=(-)50mA$	(-)0.7	(-)1.6	(-)3.0	V
Input Resistance	R1		1.5	2.2	2.9	k $\Omega$
Resistance Ratio	R1/R2		0.198	0.22	0.242	

Electrical Connection



■ No products described or contained herein are intended for use in surgical implants, life-support systems, aerospace equipment, nuclear power control systems, vehicles, disaster/crime-prevention equipment and the like, the failure of which may directly or indirectly cause injury, death or property loss.

■ Anyone purchasing any products described or contained herein for an above-mentioned use shall:

- ① Accept full responsibility and indemnify and defend SANYO ELECTRIC CO., LTD., its affiliates, subsidiaries and distributors and all their officers and employees, jointly and severally, against any and all claims and litigation and all damages, cost and expenses associated with such use;
- ② Not impose any responsibility for any fault or negligence which may be cited in any such claim or litigation on SANYO ELECTRIC CO., LTD., its affiliates, subsidiaries and distributors or any of their officers and employees jointly or severally.

■ Information (including circuit diagrams and circuit parameters) herein is for example only; it is not guaranteed for volume production. SANYO believes information herein is accurate and reliable, but no guarantees are made or implied regarding its use or any infringements of intellectual property rights or other rights of third parties.

This catalog provides information as of July, 1998. Specifications and information herein are subject to change without notice.